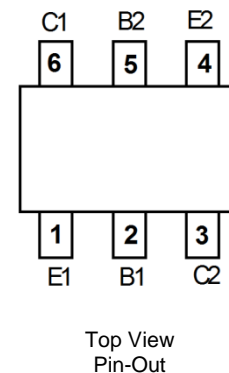
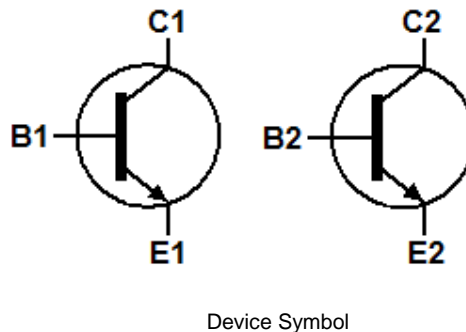
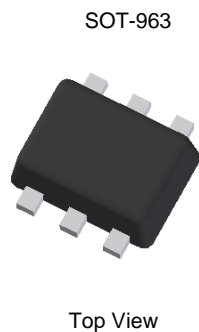


Features

- Dual NPN SS
- $BV_{CEO} > 45V$
- $I_C = 100mA$ High Collector Current
- $P_D = 300mW$ Power Dissipation
- $1mm^2$ Package Footprint, 5 Times Smaller than SOT23
- 0.5mm Height Package Minimizing Off-Board Profile
- Complementary PNP Type Available (DST857BDJ)
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: SOT-963
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208③
- Weight: 0.0027 grams (Approximate)

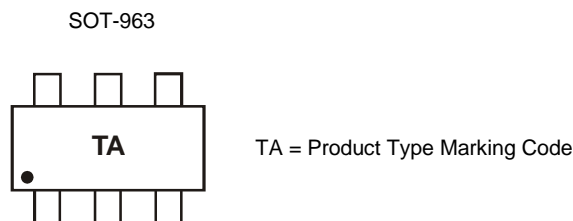


Ordering Information (Note 4)

| Device | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-------------|------------|---------|--------------------|-----------------|-------------------|
| DST847BDJ-7 | AEC-Q101 | TA | 7 | 8 | 10,000 |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | 50 | V |
| Collector-Emitter Voltage | V _{CEO} | 45 | V |
| Emitter-Base Voltage | V _{EBO} | 6.0 | V |
| Collector Current | I _C | 100 | mA |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 5) | P _D | 300 | mW |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{θJA} | 417 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

ESD rating (Note 6)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 200 | V | B |

- Notes:
- For the device mounted on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady state condition.
 - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information

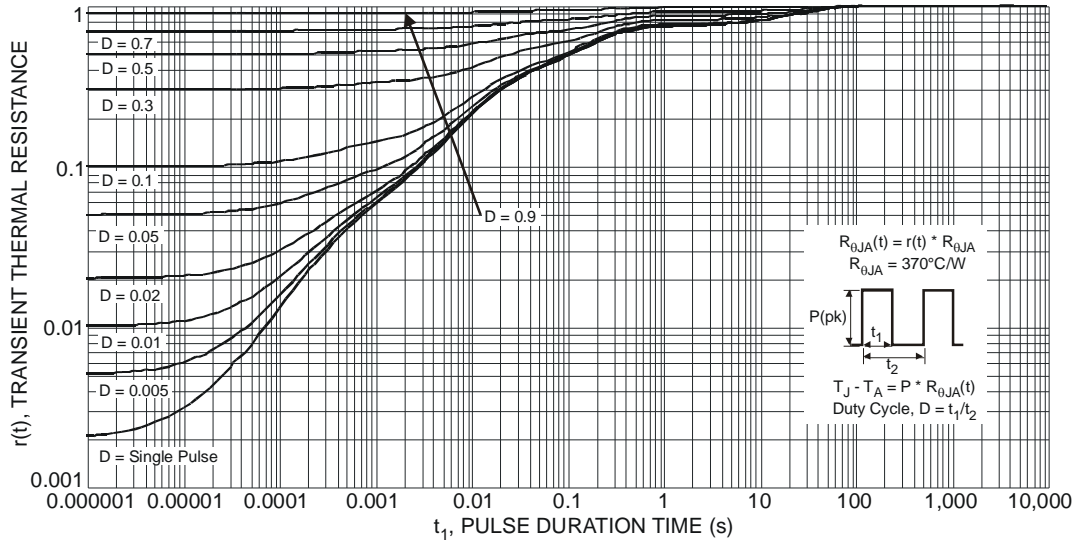


Fig. 1 Transient Thermal Response

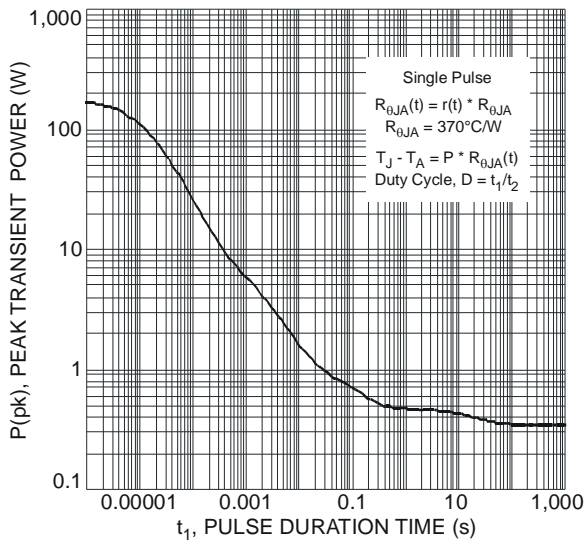


Fig. 2 Single Pulse Maximum Power Dissipation

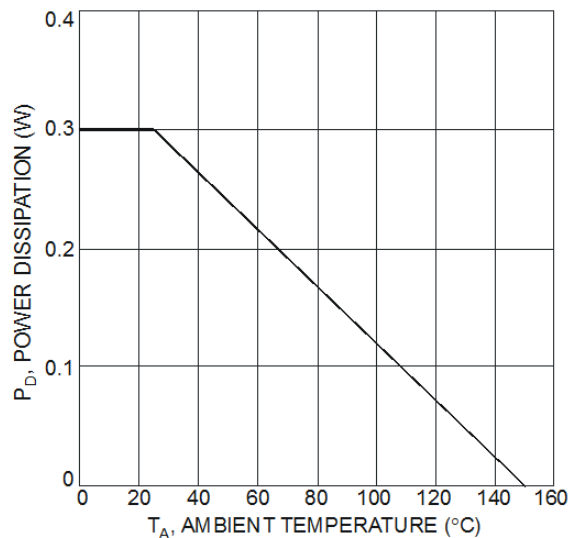


Fig. 3 Power Dissipation vs. Ambient Temperature

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic (Note 7) | Symbol | Min | Typical | Max | Unit | Test Condition |
|--------------------------------------|----------------------|----------|------------|----------------|------|---|
| Collector-Base Breakdown Voltage | BV _{CBO} | 50 | 150 | – | V | I _C = 10μA, I _B = 0 |
| Collector-Emitter Breakdown Voltage | BV _{CES} | 50 | 150 | – | V | I _C = 10μA, I _B = 0 |
| Collector-Emitter Breakdown Voltage | BV _{CEO} | 45 | 65 | – | V | I _C = 1mA, I _B = 0 |
| Emitter-Base Breakdown Voltage | BV _{EBO} | 6 | 8.35 | – | V | I _E = 1μA, I _C = 0 |
| Collector-Base Cut-Off Current | I _{CBO} | – | – | 15 | nA | V _{CB} = 30V |
| DC Current Gain | h _{FE} | – 200 | 220 300 | – 470 | – | I _C = 10μA, V _{CE} = 5V I _C = 2.0mA, V _{CE} = 5V |
| Collector-Emitter Saturation Voltage | V _{CE(sat)} | – | 50 122 | 125 300 | mV | I _C = 10mA, I _B = 0.5mA I _C = 100mA, I _B = 5.0mA |
| Base-Emitter Saturation Voltage | V _{BE(sat)} | – | 760 880 | 1,000 1,100 | mV | I _C = 10mA, I _B = 0.5mA I _C = 100mA, I _B = 5.0mA |
| Base-Emitter Voltage | V _{BE(on)} | 580 | 650 725 | 750 800 | mV | I _C = 2.0mA, V _{CE} = 5V I _C = 10mA, V _{CE} = 5V |
| Current Gain-Bandwidth Product | f _T | 100 | 170 | – | MHz | V _{CE} = 5V, I _C = 10mA, f = 100MHz |
| Collector-Base Capacitance | C _{cbo} | – | 1.5 | – | pF | V _{CB} = 10V, f = 1.0MHz |

Note: 7. Measured under pulsed conditions. Pulse width ≤ 300 μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

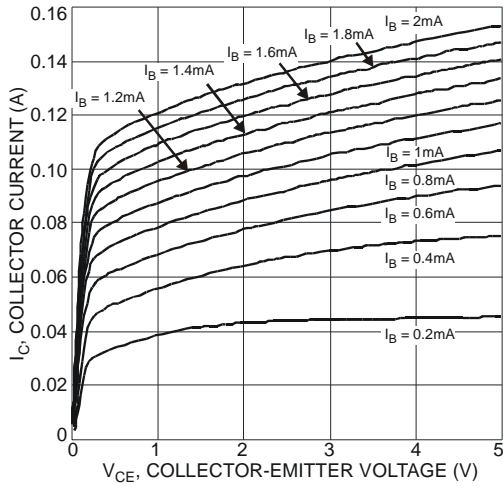


Fig. 4 Typical Collector Current vs. Collector-Emitter Voltage

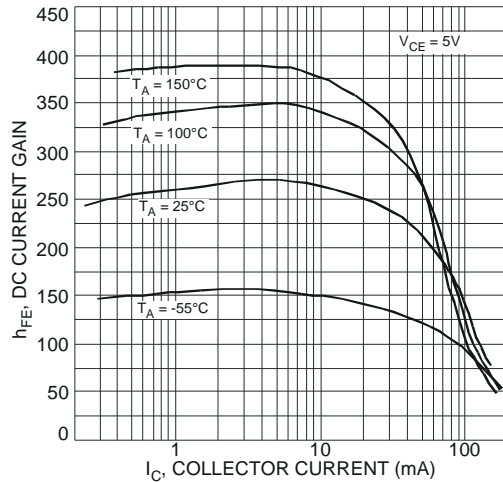


Fig. 5 Typical DC Current Gain vs. Collector Current

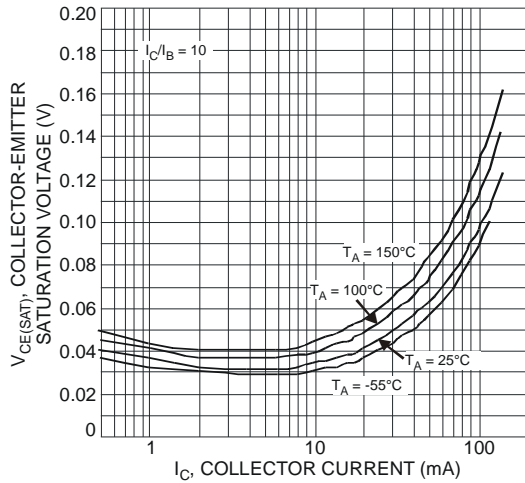


Fig. 6 Typical Collector-Emitter Saturation Voltage vs. Collector Current

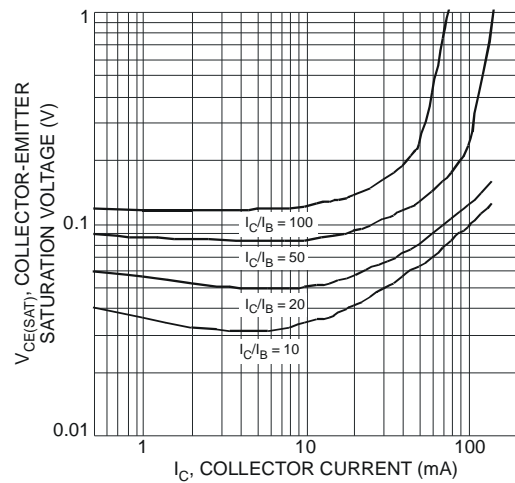


Fig. 7 Typical Collector-Emitter Saturation Voltage vs. Collector Current

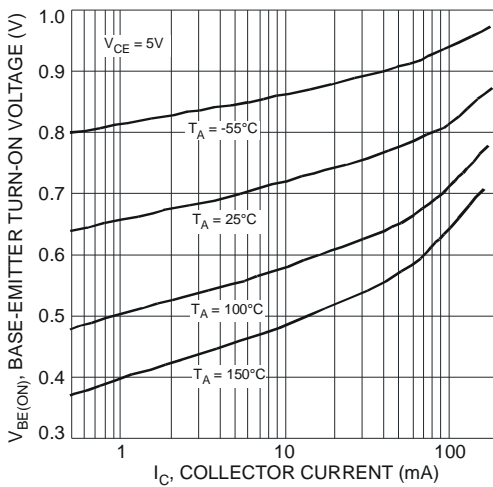


Fig. 8 Typical Base-Emitter Turn-On Voltage vs. Collector Current

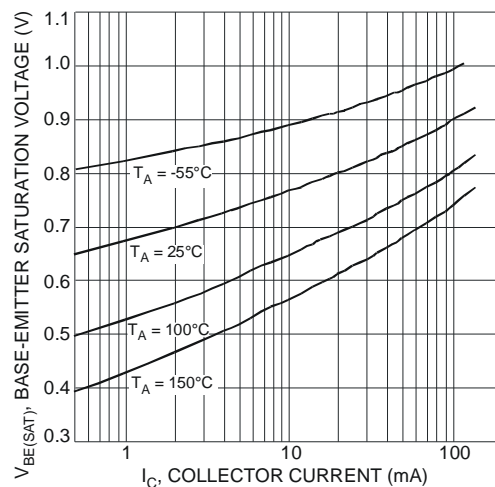
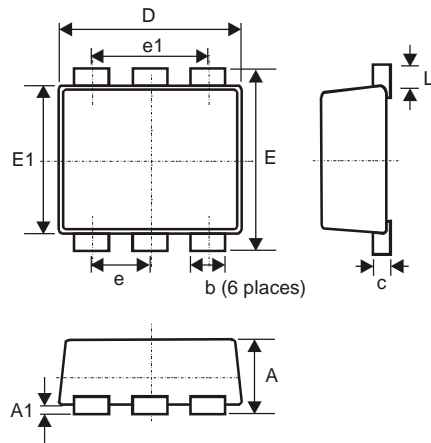


Fig. 9 Typical Base-Emitter Saturation Voltage vs. Collector Current

Package Outline Dimensions

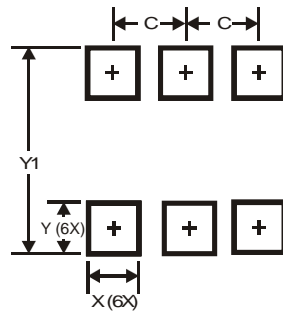
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



| SOT-963 | | | |
|-----------------------------|----------|-------|-------|
| Dim | Min | Max | Typ |
| A | 0.40 | 0.50 | 0.45 |
| A1 | 0 | 0.05 | - |
| C | 0.120 | 0.180 | 0.150 |
| D | 0.95 | 1.05 | 1.00 |
| E | 0.95 | 1.05 | 1.00 |
| E1 | 0.75 | 0.85 | 0.80 |
| L | 0.05 | 0.15 | 0.10 |
| b | 0.10 | 0.20 | 0.15 |
| e | 0.35 Typ | | |
| e1 | 0.70 Typ | | |
| All Dimensions in mm | | | |

Suggest Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 0.350 |
| X | 0.200 |
| Y | 0.200 |
| Y1 | 1.100 |

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